### 1. General description

PNP high power bipolar transistor in a power DPAK, TO-252 (SOT428C) Surface-Mounted Device (SMD) plastic package.

NPN complement: MJD31C

### 2. Features and benefits

- · High thermal power dissipation capability
- · High energy efficiency due to less heat generation
- · Electrically similar to popular MJD32 series
- Low collector emitter saturation voltage
- Fast switching speeds

## 3. Applications

- Power management
- Load switch
- Linear mode voltage regulator
- · Constant current drive backlighting application
- Motor drive
- · Relay replacement

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-100	V
I <sub>C</sub>	collector current		-	-	-3	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	-5	Α
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -4 V; I <sub>C</sub> = -1 A; T <sub>amb</sub> = 25 °C	25	-	-	
		V <sub>CE</sub> = -4 V; I <sub>C</sub> = -3 A; T <sub>amb</sub> = 25 °C	10	-	50	



100 V, 3 A PNP high power bipolar transistor

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	mb	Ē.
2	С	collector		В -{м
3	E	emitter		C; mb
mb	С	mounting base; connected to collector	1 3	aaa-029523
			DPAK (SOT428C)	

### 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package		
	Name	Description	Version
MJD32C	DPAK	Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428C

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
MJD32C	MJD32C

# 8. Limiting values

#### Table 5. Limiting values

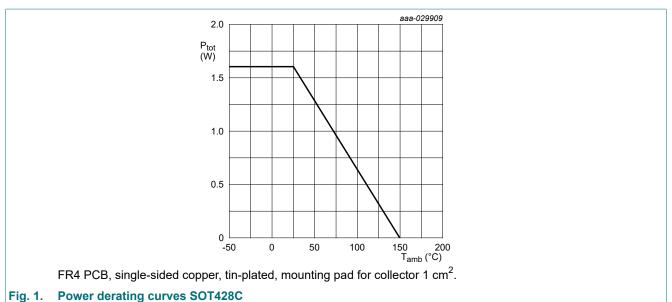
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base		-	-100	V
$V_{EBO}$	emitter-base voltage	open collector		-	-6	V
I <sub>C</sub>	collector current			-	-3	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-5	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> ≤ 25 °C	[1]	-	15	W
		T <sub>amb</sub> ≤ 25 °C	[2]	-	1.6	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Total power dissipation junction to mounting base.

<sup>[2]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.

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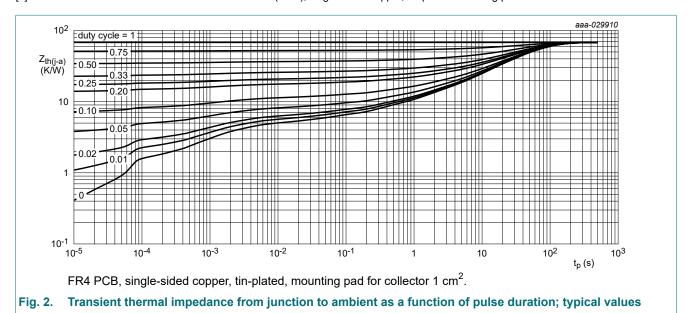


### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	in free air		-	-	9	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient		[1]	-	-	79	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.



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### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CES</sub>	collector-emitter cut-off	V <sub>CE</sub> = -80 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	-1	μΑ
	current	V <sub>CE</sub> = -80 V; V <sub>BE</sub> = 0 V; T <sub>j</sub> = 150 °C	-	-	-50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-1	μA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -4 V; I <sub>C</sub> = -1 A; T <sub>amb</sub> = 25 °C	25	-	-	
		V <sub>CE</sub> = -4 V; I <sub>C</sub> = -3 A; T <sub>amb</sub> = 25 °C	10	-	50	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -3 \text{ A}; I_B = -375 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	-	-1.2	V
$V_{BE}$	base-emitter voltage	$V_{CE}$ = -4 V; $I_{C}$ = -3 mA; $T_{amb}$ = 25 °C	-	-	-1.8	V
h <sub>fe</sub>	small-signal current gain	$V_{CE}$ = -10 V; $I_{C}$ = -500 A; f = 1 kHz; $T_{amb}$ = 25 °C	20	-	-	
f <sub>T</sub>	transition frequency	$V_{CE}$ = -10 V; $I_{C}$ = -500 mA; f = 1 MHz; $T_{amb}$ = 25 °C	3	-	-	MHz

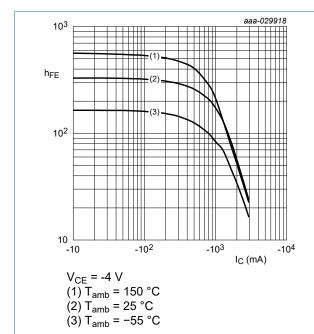


Fig. 3. DC current gain as a function of collector current; typical values

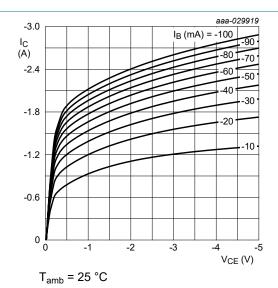
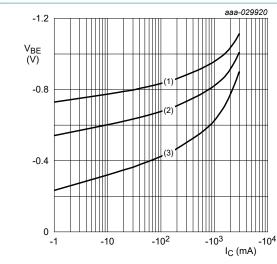


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

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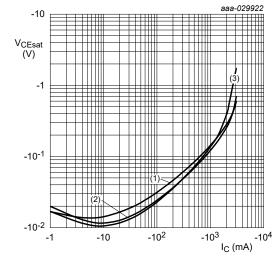


$$V_{CE} = -5 V$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. Base-emitter voltage as a function of collector current; typical values



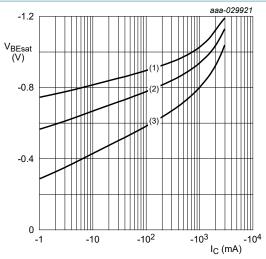
$$I_{\rm C}/I_{\rm B} = 10$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



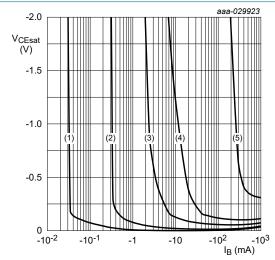
$$I_{\rm C}/I_{\rm B} = 10$$

$$I_{C}/I_{B} = 10$$
  
(1)  $T_{amb} = -55 \,^{\circ}C$   
(2)  $T_{amb} = 25 \,^{\circ}C$   
(3)  $T_{amb} = 150 \,^{\circ}C$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



(1)  $I_C = -10 \text{ mA}$ 

$$(2) I_C = -100 \text{ mA}$$

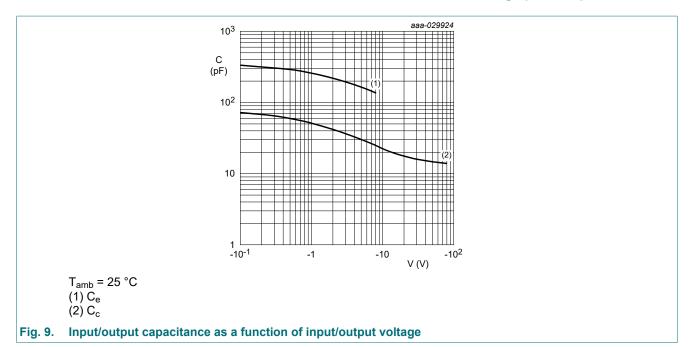
(3) 
$$I_C = -500 \text{ mA}$$

$$(4) I_C = -1000 \text{ mA}$$

$$(5) I_C = -3000 \text{ mA}$$

Fig. 8. Collector-emitter saturation region as a function of base current; typical values

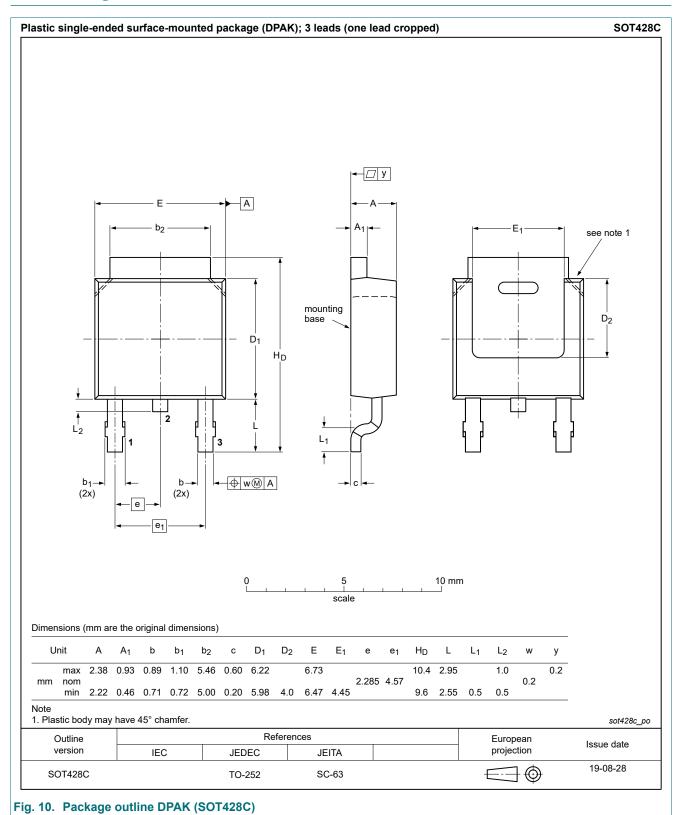
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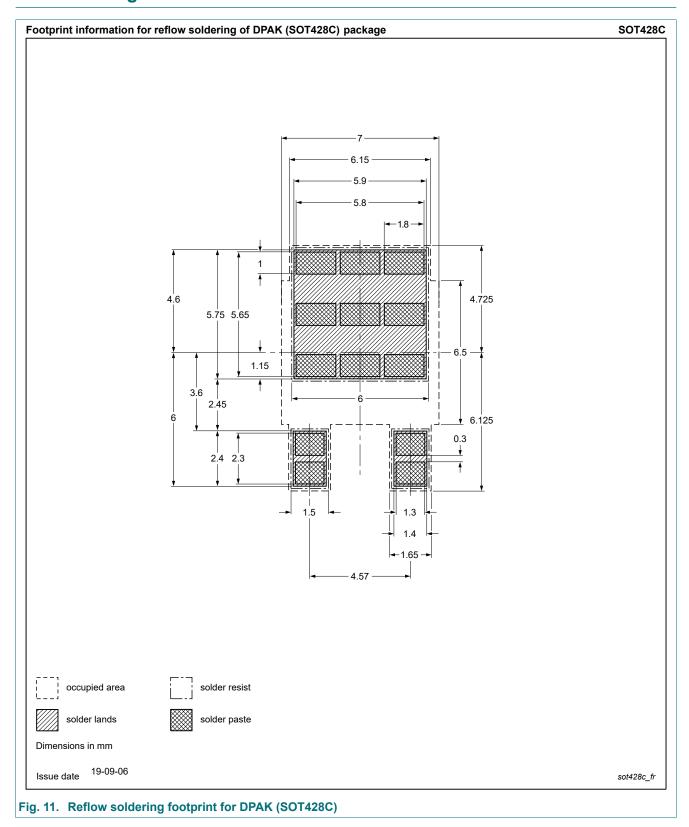
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# 11. Package outline



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# 12. Soldering



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# 13. Revision history

#### Table 8. Revision history

Table 6. INEVISION I	iistoi y			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
MJD32C v.6	20190930	Product data sheet	-	MJD32C v.5
Modifications:	Thermal character	cteristics: Figure 2 adapted		,
MJD32C v.5	20190912	Product data sheet	-	MJD32C v.4
MJD32C v.4	20190802	Product data sheet	-	MJD32C v.3
MJD32C v.3	20190729	Product data sheet	-	MJD32C v.2
MJD32C v.2	20190523	Preliminary data sheet	-	MJD32C v.1
MJD32C v.1	20190418	Preliminary data sheet	-	-

### 14. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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